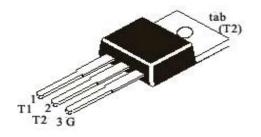


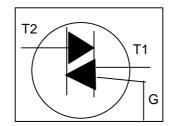
Continental Device India Limited

An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company



TRIAC BT136D





TO-220 Plastic Package

For use in General Purpose Bidirectional Switching and Phase Control Applications

ABSOLUTE MAXIMUM RATINGS

DADAMETED	0)//4001	TEGT COMPLETION	\/A	
PARAMETER	SYMBOL	TEST CONDITION	VALUE	UNIT
Repetitive Peak Off State Voltage	V_{DRM}		600	V
RMS on State Current	I _{T (RMS)}	full sine wave, T _{mb} ≤107°C	4.0	Α
Non Repetitive Peak on State Current	l-ou	full sine wave, T _J =25°C prior		
Non Repetitive Feak on State Guirent	I _{TSM}	to Surge		
		t=20ms	25	Α
		t=16.7ms	27	Α
I ² t for Fusing	l ² t	t=10ms	3.1	A^2s
Repetitive Rate of Rise of on State	dl _⊤ /dt	$I_{TM}=6A, I_{G}=0.2A,$		
Current After Triggering	ui _T /ut	dl _G /dt=0.2A/μs		
		T2+ G+	50	A/μs
		T2+ G-	50	A/μs
		T2- G-	50	A/μs
		T2- G+	10	A/μs
Peak Gate Current	I _{GM}		2.0	Α
Peak Gate Voltage	V_{GM}		5.0	V
Peak Gate Power	P_{GM}		5.0	W
Average Gate Power	P _{G (AV)}	Over any 20ms period	0.5	W
Storage Temperature	T_{stg}		- 40 to 150	°С
Operating Junction Temperature	T _j		125	°C

THERMAL RESISTANCE

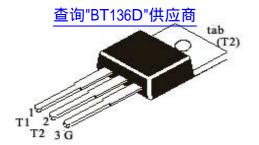
THERMAL REGISTANCE					
Junction to Mounting Base	R _{th (j-mb)}	full cycle	3.0 max	K/W	
		half cycle	3.7 max	K/W	
Junction to Ambient	R _{th (j-a)}	in free air	60 typ	K/W	

ELECTRICAL CHARACTERISTICS (T_J=25°C unless specified otherwise)

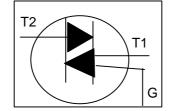
PARAMETER	SYMBOL	TEST CONDITION	MIN	MAX	UNIT
Gate Trigger Current	I _{GT}	V _D =12V, I _T =0.1A			
		T2+ G+		5.0	mΑ
		T2+ G-		5.0	mΑ
		T2- G-		5.0	mΑ
		T2- G+		10	mΑ

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ELECTRICAL CHARACTERISTICS (T_J=25°C unless specified otherwise)

PARAMETER	SYMBOL	TEST CONDITION	MIN	MAX	UNIT
Latching Current	ار	V _D =12V, I _{GT} =0.1A			
		T2+ G+		10	mA
		T2+ G-		15	mA
		T2- G-		10	mA
		T2- G+		30	mA
Holding Current	I _H	$V_{D}=12V, I_{GT}=0.1A$		10	mΑ
On State Voltage	V_{T}	I _T =5A		1.7	V
Gate Trigger Voltage	V_{GT}	$V_D = 12V, I_T = 0.1A$		1.5	V
		V _D =400V, I _T =0.1A,T _J =125°C	0.25		V
Off State Leakage Current	I _D	$V_D = V_{DRM} = max, T_J = 125^{\circ}C$		0.5	mA

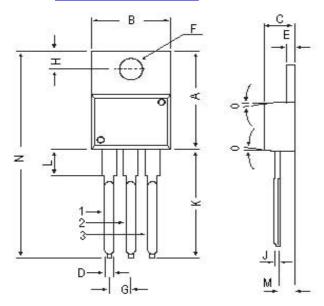
DYNAMIC CHARACTERISTICS

DINAMIC CHARACTERICITION								
PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT		
Critical Rate of Rise of off State Voltage	d _{VD} /dt	$\begin{array}{c} V_{DM}\text{=}67\%\ V_{DRM}\text{=}max, \\ T_J\text{=}125^{\circ}\text{C, exponential} \\ waveform, gate open circuit, \\ R_{GK}\text{=}1\text{K}\Omega \end{array}$		5		V/µs		
Gate Controlled turn on time	t _{gt}	I_{TM} =6A, V_D = V_{DRM} max, I_G =0.1A, dI_G / dt =5A/ μ s		2		μs		

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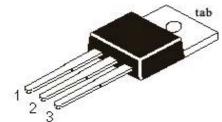
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TO-220 Plastic Package



DIM	MIN	MAX		
Α	14.42	16.51		
В	9.63	10.67		
С	3.56	4.83		
D	0.2_	0.90		
E	1.15	1.40		
F	3.75	3.88		
G	2.29	2.79		
Н	2.54	3.43		
J		0.56		
К	12.70	14.73		
L	2.80	4.07		
М	2.03	2.92		
N		31.24		
0	7 DEG			

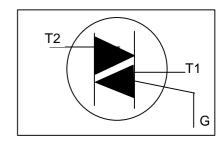
All diminsions in mm.



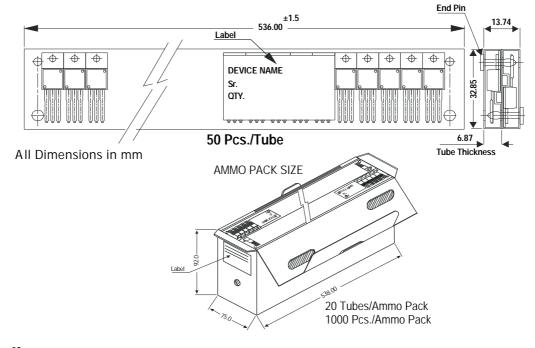
Pin Configuration

- 1. Main Terminal 1
- 2. Main Terminal 2
- 3. Gate

tab Main Terminal 2



TO-220 Tube Packing



Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size Oty		GrWt
TO-220	200 pcs/polybag	396 gm/200 pcs	3" x 7.5" x 7.5"	1.OK	17" x 15" x 13.5"	16.0K	36 kgs
	50 pcs/tube	120 gm/50 pcs	3.5" x 3.7" x 21.5"	1.0K	19" x 19" x 19"	10.0K	29 kgs

Customer Notes BT136D

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TO-220 Plastic Package

Disclaimer

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